# Old Company Name in Catalogs and Other Documents

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# RENESAS BCR20AM-12LB

Triac

Medium Power Use

(The product guaranteed maximum junction temperature of 150°C)

REJ03G0458-0300 Rev.3.00 Nov 30, 2007

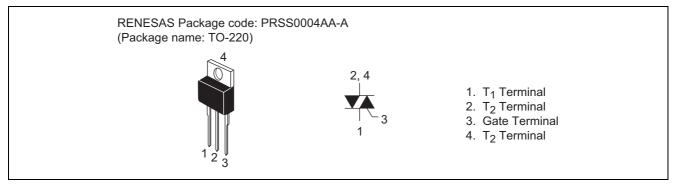
# Features

- I<sub>T (RMS)</sub> : 20 A
- $V_{DRM}$  : 600 V
- $I_{FGTI}$ ,  $I_{RGTI}$ ,  $I_{RGT III}$ : 30 mA (20 mA)<sup>Note6</sup>

### • Non-Insulated Type

Planar Passivation Type

# Outline



# Applications

Vacuum cleaner, electric heater, light dimmer, copying machine, and controller for other motor and heater

# Warning

- 1. Refer to the recommended circuit values around the triac before using.
- 2. Be sure to exchange the specification before using. Otherwise, general triacs with the maximum junction temperature of 125°C will be supplied.

# Maximum Ratings

| Parameter  | Symbol           | Voltage class<br>12 | - Unit |
|--|------------------|---------------------|--------|
| Repetitive peak off-state voltage <sup>Note1</sup>     | V <sub>DRM</sub> | 600                 | V      |
| Non-repetitive peak off-state voltage <sup>Note1</sup> | V <sub>DSM</sub> | 720                 | V      |

#### BCR20AM-12LB (The product guaranteed maximum junction temperature of 150°C)

| Parameter                      | Symbol               | Ratings      | Unit             | Conditions   |
|--------------------------------|----------------------|--------------|------------------|--|
| RMS on-state current           | I <sub>T (RMS)</sub> | 20           | A                | Commercial frequency, sine full wave $360^{\circ}$ conduction, Tc = $134^{\circ}C^{Note3}$ |
| Surge on-state current         | I <sub>TSM</sub>     | 200          | A                | 60Hz sinewave 1 full cycle, peak value, non-repetitive                                     |
| l <sup>2</sup> t for fusing    | l <sup>2</sup> t     | 167          | A <sup>2</sup> s | Value corresponding to 1 cycle of half<br>wave 60Hz, surge on-state current                |
| Peak gate power dissipation    | P <sub>GM</sub>      | 5            | W                |  |
| Average gate power dissipation | P <sub>G (AV)</sub>  | 0.5          | W                |  |
| Peak gate voltage              | V <sub>GM</sub>      | 10           | V                |  |
| Peak gate current              | I <sub>GM</sub>      | 2            | A                |  |
| Junction temperature           | Tj                   | - 40 to +150 | °C               |  |
| Storage temperature            | Tstg                 | - 40 to +150 | °C               |  |
| Mass                           | —                    | 2.0          | g                | Typical value  |

Notes: 1. Gate open.

# **Electrical Characteristics**

| Parameter   |     | Symbol                | Min.    | Тур. | Max.                | Unit | Test conditions  |  |
|---|-----|-----------------------|---------|------|---------------------|------|--|--|
| Repetitive peak off-state current                                       |     | I <sub>DRM</sub>      | —       | _    | 2.0/3.0             | mA   | Tj = 125°C/150°C, V <sub>DRM</sub> applied                         |  |
| On-state voltage  |     | V <sub>TM</sub>       | —       | _    | 1.5                 | V    | $Tc = 25^{\circ}C$ , $I_{TM} = 30$ A,<br>Instantaneous measurement |  |
| Gate trigger voltage <sup>Note2</sup>                                   | Ι   | $V_{FGTI}$            | —       | _    | 1.5                 | V    | $Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$                     |  |
|   | II  | V <sub>RGTI</sub>     | —       | _    | 1.5                 | V    | $R_G = 330 \Omega$   |  |
|   | III | V <sub>RGTIII</sub>   | —       |      | 1.5                 | V    |  |  |
| Gate trigger current <sup>Note2</sup>                                   | Ι   | $I_{FGTI}$            | —       |      | 30 <sup>Note6</sup> | mA   | $Tj = 25^{\circ}C, V_{D} = 6 V, R_{L} = 6 \Omega,$                 |  |
|   | II  | I <sub>RGTI</sub>     | —       |      | 30 <sup>Note6</sup> | mA   | R <sub>G</sub> = 330 Ω   |  |
|   | III | I <sub>RGTIII</sub>   | _       | _    | 30 <sup>Note6</sup> | mA   |  |  |
| Gate non-trigger voltage  |     | $V_{GD}$              | 0.2/0.1 | _    | _                   | V    | $Tj = 125^{\circ}C/150^{\circ}C, V_D = 1/2 V_{DRM}$                |  |
| Thermal resistance  |     | R <sub>th (j-c)</sub> | —       | _    | 0.8                 | °C/W | Junction to case <sup>Note3 Note4</sup>                            |  |
| Critical-rate of rise of off-state commutating voltage <sup>Note5</sup> |     | (dv/dt)c              | 10/1    |      | —                   | V/µs | Tj = 125°C/150°C   |  |

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

3. Case temperature is measured at the  $T_2$  tab 1.5 mm away from the molded case.

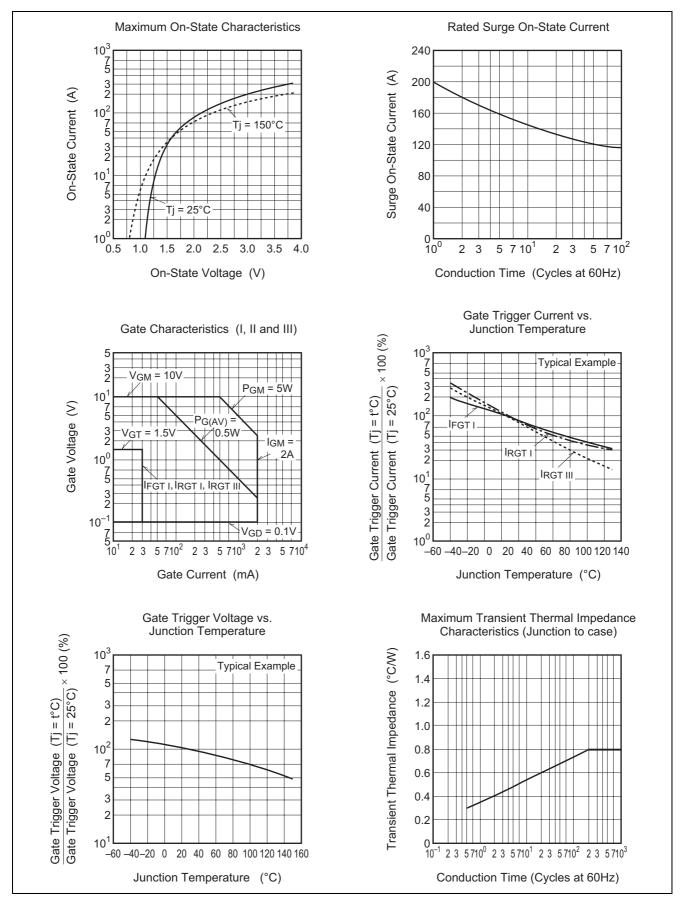
4. The contact thermal resistance R<sub>th (c-f)</sub> in case of greasing is 1.0°C/W.

5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

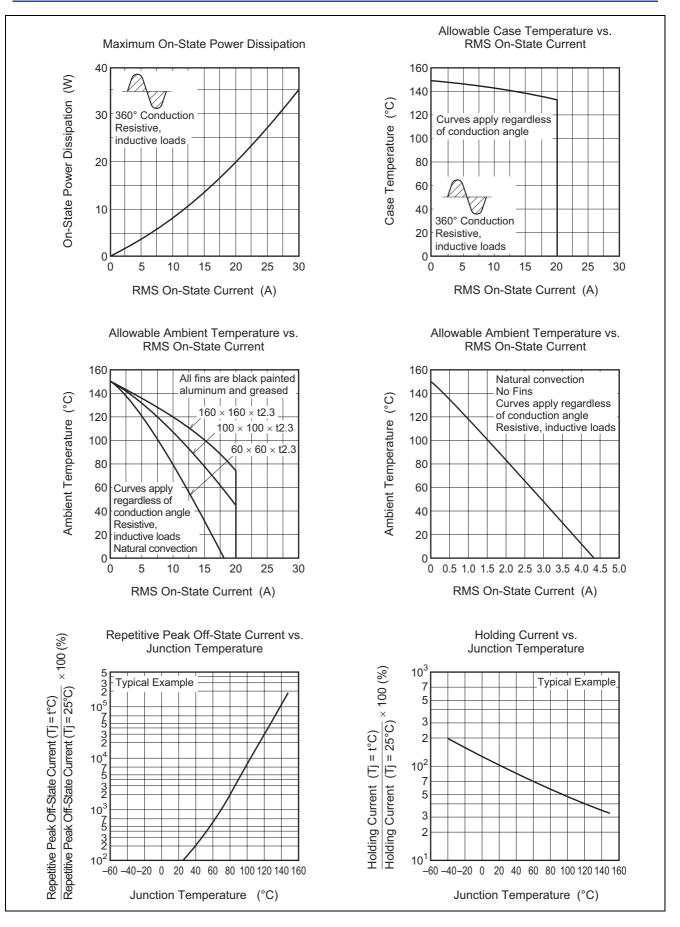
6. High sensitivity (I\_{GT}  $\leq 20$  mA) is also available. (I\_{GT} item: 1)

| Test conditions   | Commutating voltage and current waveforms<br>(inductive load) |
|---|---|
| 1. Junction temperature<br>Tj = 125°C/150°C                             | Supply Voltage → Time   |
| 2. Rate of decay of on-state commutating current<br>(di/dt)c = -10 A/ms | Main Current<br>→ Time  |
| 3. Peak off-state voltage $V_D = 400 \text{ V}$                         | Main Voltage → Time<br>(dv/df)c V <sub>D</sub>                |

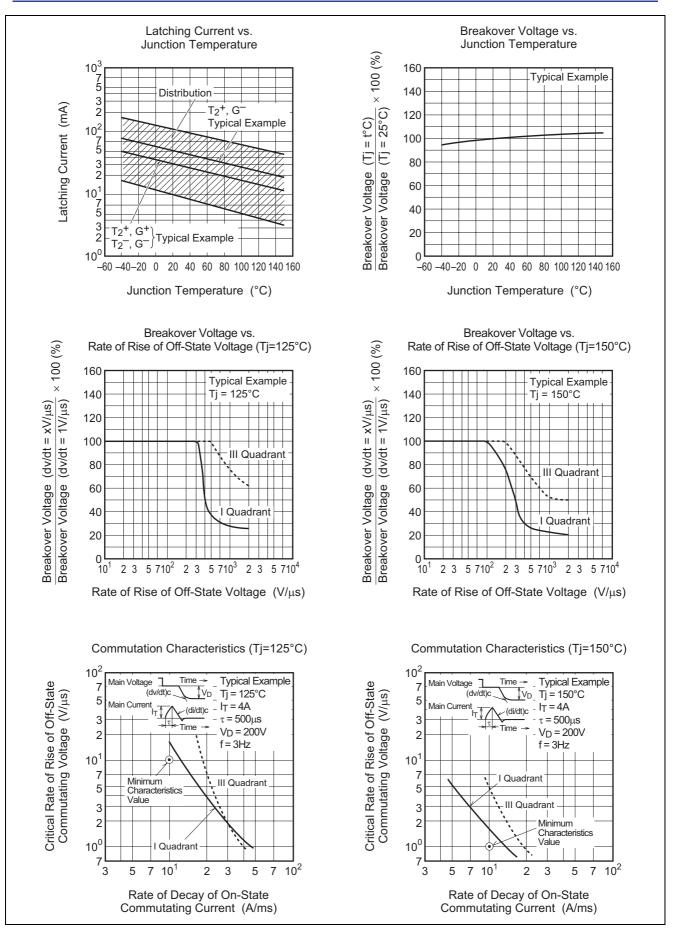
### **Performance Curves**

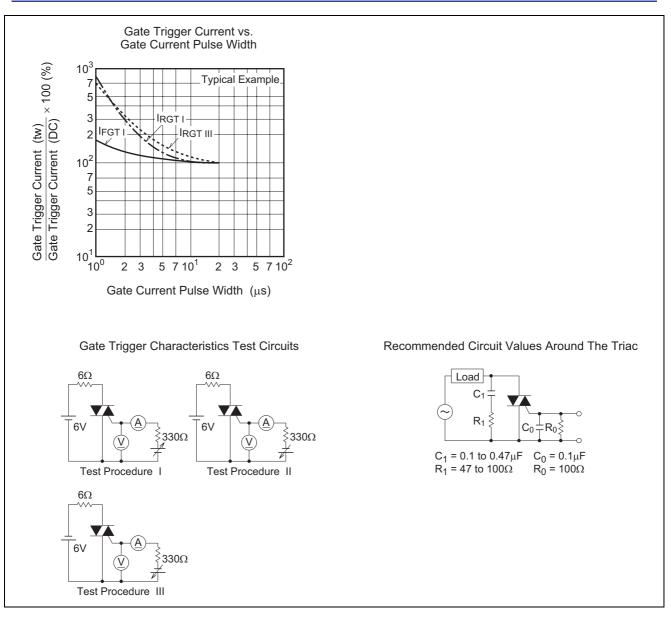


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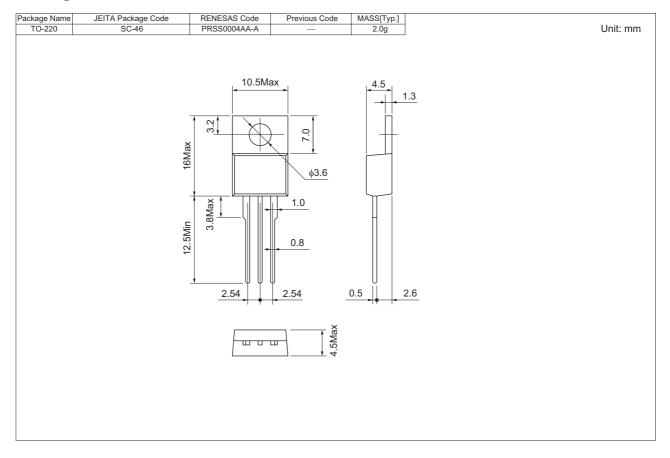


#### BCR20AM-12LB (The product guaranteed maximum junction temperature of 150°C)





### Package Dimensions



#### **Order Code**

| Lead form     | Standard packing        | Quantity | Standard order code           | Standard order<br>code example |
|---------------|-------------------------|----------|-------------------------------|--------------------------------|
| Straight type | Vinyl sack              | 100      | Type name                     | BCR20AM-12LB                   |
| Lead form     | Plastic Magazine (Tube) | 50       | Type name – Lead forming code | BCR20AM-12LB-A8                |

Note : Please confirm the specification about the shipping in detail.

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